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# N-Channel 12 V (D-S) MOSFET

### **DESCRIPTION**

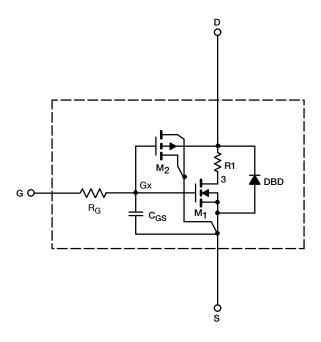
The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the -  $55\,^{\circ}$ C to 125  $^{\circ}$ C temperature ranges under the pulsed 0 V to 4.5 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched  $C_{gd}$  model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

### **CHARACTERISTICS**

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- · Model the Gate Charge

### SUBCIRCUIT MODEL SCHEMATIC



## Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



# **SPICE Device Model Si4866BDY**

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<b>SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	0.42	-	V
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \le 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	96	-	Α
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = 4.5 \text{ V}, I_D = 12 \text{ A}$	0.0042	0.0042	Ω
		$V_{GS} = 2.5 \text{ V}, I_D = 10 \text{ A}$	0.0049	0.0048	
		V <sub>GS</sub> = 1.8 V, I <sub>D</sub> = 8 A	0.0056	0.0060	
Forward Transconductancea	9 <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 12 A	89	80	S
Diode Forward Voltage	V <sub>SD</sub>	I <sub>F</sub> = 9.5 A	0.51	0.62	V
Dynamic <sup>b</sup>					
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 6 V, V <sub>GS</sub> = 0 V, f = 1 MHz	5401	5020	pF
Output Capacitance	Coss		1289	1305	
Reverse Transfer Capacitance	C <sub>rss</sub>		870	805	
Total Gate Charge	0	$V_{DS} = 6 \text{ V}, V_{GS} = 4.5 \text{ V}, I_D = 10 \text{ A}$	46	52	nC
	$Q_g$	V <sub>DS</sub> = 6 V, V <sub>GS</sub> = 2.5 V, I <sub>D</sub> = 10 A	29	29.5	
Gate-Source Charge	Q <sub>gs</sub>		6.2	6.2	
Gate-Drain Charge	Q <sub>ad</sub>		8.9	8.9	

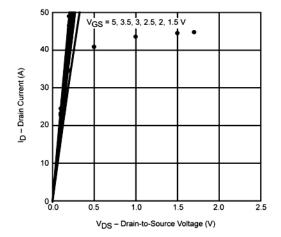
#### Notes

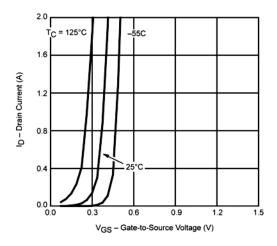
- a. Pulse test; pulse width  $\leq 300~\mu s,~duty~cycle \leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

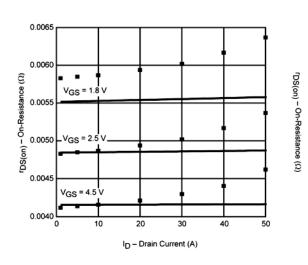
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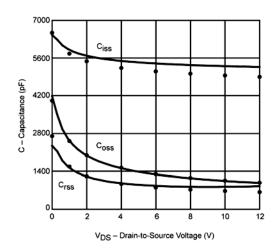
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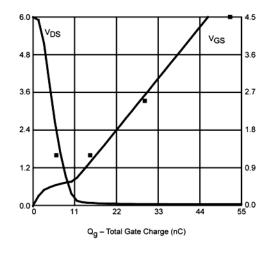
## COMPARISON OF MODEL WITH MEASURED DATA (T<sub>J</sub> = 25 °C, unless otherwise noted)

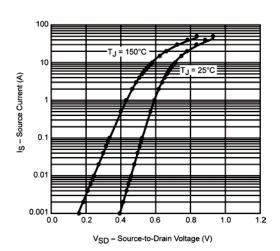












#### Note

• Dots and squares represent measured data.



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